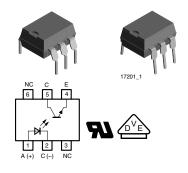
## **Vishay Semiconductors**

## **Optocoupler, Phototransistor Output**



### DESCRIPTION

The TCDT1110/TCDT1110G consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6 pin plastic dual inline package. The elements provide a fixed distance between input and output for highest safety requirements.

### **VDE STANDARDS**

These couplers perform safety functions according to the following equipment standards:

• DIN EN 60747-5-5

Optocoupler for electrical safety requirements

- + IEC 60950/EN 60950 Office machines (applied for reinforced isolation for mains voltage  $\leq$  400  $V_{RMS})$
- VDE 0804

Telecommunication apparatus and data processing

• IEC 60065

Safety for mains-operated electronic and related household apparatus

### FEATURES

- Extra low coupling capacity typical 0.2 pF
- High Common Mode Rejection
- Low temperature coefficient of CTR
- Base not connected
- · Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### APPLICATIONS

- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
  - For appl. class I IV at mains voltage  $\leq$  300 V - For appl. class I - III at mains voltage  $\leq$  600 V according DIN EN 60747-5-5.

### AGENCY APPROVALS

- UL1577, File No. E76222 System Code A, Double Protection
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-5 pending
- FIMKO

ORDER INFORMATION					
PART	REMARKS				
TCDT1110	CTR > 100 %, DIP-6				
TCDT1110G	CTR > 100 %, DIP-6				

#### Note

G = Leadform 10.16 mm; G is not marked on the body.

ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V <sub>R</sub>	6	V				
Forward current		I <sub>F</sub>	60	mA				
Forward surge current	$t_p/T \le 10 \ \mu s$	I <sub>FSM</sub>	3	A				
Power dissipation		P <sub>diss</sub>	100	mW				
Junction temperature		Tj	125	°C				



## Vishay Semiconductors

### Optocoupler, Phototransistor Output



PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
OUTPUT			• • •	
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		Ι <sub>C</sub>	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation		P <sub>diss</sub>	150	mW
Junction temperature		Tj	125	°C
COUPLER			· ·	
Isolation test voltage (RMS)	t = 1 min	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Total power dissipation		P <sub>tot</sub>	250	mw
Ambient temperature range		T <sub>amb</sub>	- 55 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 55 to + 125	°C
Soldering temperature <sup>(2)</sup>	2 mm from case t $\leq$ 10 s	T <sub>sld</sub>	260	°C

#### Notes

(1) T<sub>amb</sub> = 25 °C unless otherwise specified. Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I <sub>F</sub> = 50 mA	VF		1.2	1.5	V
Junction capacitance	$V_{R} = 0$ , f = 1 MHz	Cj		50		pF
OUTPUT						
Collector emitter voltage	$I_{\rm C} = 1  \rm{mA}$	V <sub>CEO</sub>	70			V
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V
Collector-emitter cut-off current	$V_{CE} = 30 V, I_F = 0$	I <sub>CEO</sub>			150	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 0.5 \text{ mA}$	V <sub>CEsat</sub>			0.3	V
Cut-off frequency	$V_{CE}$ = 5 V, I <sub>F</sub> = 10 mA, R <sub>L</sub> = 1 $\Omega$	f <sub>c</sub>		110		kHz
Coupling capacitance	f = 1 MHz	C <sub>k</sub>		0.3		pF

#### Note

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER R	ΑΤΙΟ					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>	$V_{CE} = 20 \text{ V}, \text{ I}_{F} = 10 \text{ mA}$	CTR	100			%

MAXIMUM SAFETY RAT	INGS					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward current		١ <sub>F</sub>			130	mA
OUTPUT						
Power dissipation		P <sub>diss</sub>			265	mW
COUPLER						
Rated impulse voltage		V <sub>IOTM</sub>			6	kV
Safety temperature		T <sub>si</sub>			150	°C

#### Note

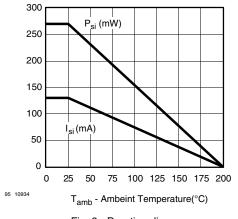
According to DIN EN 60747-5-5 see figure 1. This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

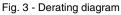


### Optocoupler, Phototransistor Output

**Vishay Semiconductors** 

INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	V <sub>pd</sub>	1.6			kV	
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V <sub>IOTM</sub>	6			kV	
lot test (sample test)		V <sub>pd</sub>	1.3			kV	
	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>			Ω	
Insulation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	10 <sup>11</sup>			Ω	
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 200 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>			Ω	





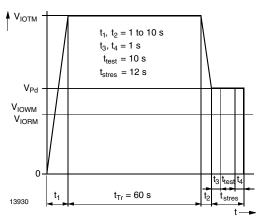
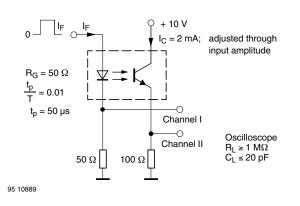
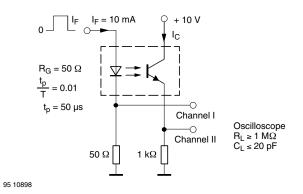


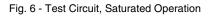
Fig. 4 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC 60747

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-off time	$V_S$ = 10 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 3)	t <sub>off</sub>		15.0		μs	
Turn-on time	$V_S$ = 10 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 3)	t <sub>on</sub>		15.0		μs	
Turn-off time	$V_{S} = 10 \text{ V}, \text{ I}_{F} = 10 \text{ mA}, \text{ R}_{L} = 1 \text{ k}\Omega$ (see figure 4)	t <sub>off</sub>		18.0		μs	
Turn-on time	$V_{S} = 10 \text{ V}, \text{ I}_{F} = 10 \text{ mA}, \text{ R}_{L} = 1 \text{ k}\Omega$ (see figure 4)	t <sub>on</sub>		9.0		μs	





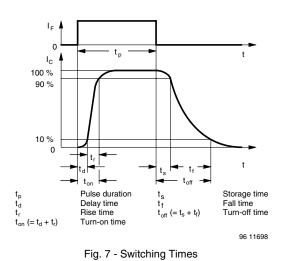




## **Vishay Semiconductors**

Optocoupler, Phototransistor Output





## TYPICAL CHARACTERISTICS

T<sub>amb</sub> = 25 °C, unless otherwise specified

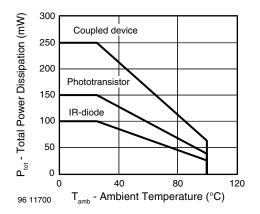


Fig. 8 - Total Power Dissipation vs. Ambient Temperature

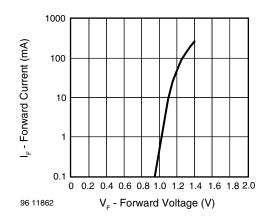


Fig. 9 - Forward Current vs. Forward Voltage

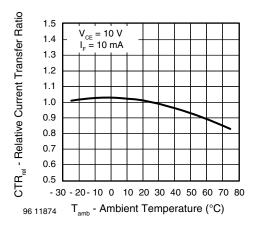


Fig. 10 - Relative Current Transfer Ratio vs. Ambient Temperature

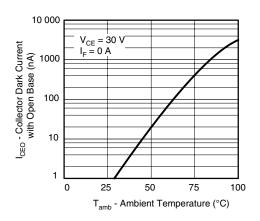


Fig. 11 - Collector Dark Current vs. Ambient Temperature



Optocoupler, Phototransistor Output **Vishay Semiconductors** 

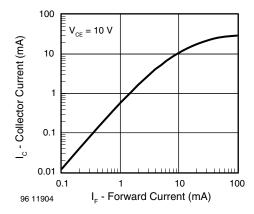


Fig. 12 - Collector Current vs. Forward Current

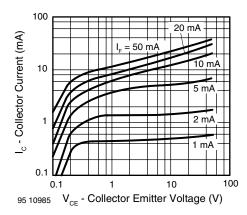


Fig. 13 - Collector Current vs. Collector Emitter Voltage

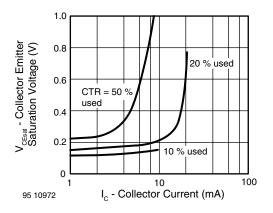


Fig. 14 - Collector Emitter Saturation Voltage vs. Collector Current

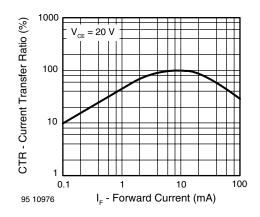


Fig. 15 - Current Transfer Ratio vs. Forward Current

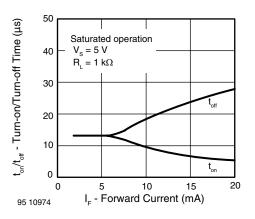


Fig. 16 - Turn-on/Turn-off Time vs. Forward Current

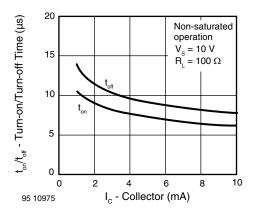
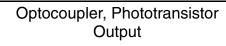
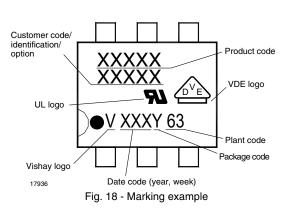


Fig. 17 - Turn-on/Turn-off Time vs. Collector Current

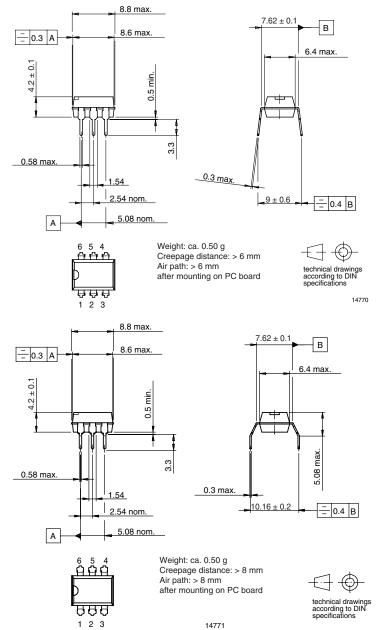
## Vishay Semiconductors







**PACKAGE DIMENSIONS** in millimeters



For technical questions, contact: optocoupler.answers@vishay.com



Optocoupler, Phototransistor Output Vishay Semiconductors

# OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.



Vishay

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